L Number Hits Search Text DB (peripheral adj portion) and 257/\$.ccls. USPAT; and (nonvolatile adj memory) US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; US-PGPUB; EPO; JPO;	Time stamp 2003/05/17 12:49
EPO; JPO; DERWENT; IBM_TDB 3 0 5659191.pn. and (gate adj length) USPAT; US-PGPUB;	
DERWENT; IBM_TDB USPAT; US-PGPUB;	
3 0 5659191.pn. and (gate adj length) IBM_TDB USPAT; US-PGPUB;	
3 0 5659191.pn. and (gate adj length) USPĀT; US-PGPUB;	
US-PGPUB;	0000 /05 /15 00 0
	2003/05/17 08:0
, , , , , , , , , , , , , , , , , , ,	
DEFO, SFO, DERWENT;	
IBM TDB	
4 0 5659191.pn. and (gate adj width) USPAT;	2003/05/17 08:08
US-PGPUB;	2000,00,21
EPO; JPO;	
DERWENT;	
IBM_TDB	
5 0 5659191.pn. and (gate adj size) USPĀT;	2003/05/17 08:08
US-PGPUB;	
EPO; JPO;	
DERWENT;	
IBM_TDB	0000/05/55 00 1
6 2 5659191.pn. and (gate) USPAT;	2003/05/17 08:12
US-PGPUB;	
EPO; JPO;	
DERWENT;	
7 1 5659191.pn. and (length or width) USPAT;	2003/05/17 09:53
US-PGPUB;	*
EPO; JPO;	·
DERWENT;	
IBM TDB	,
	2003/05/17 11:54
length) and (nonvolatile adj memory) US-PGPUB;	
EPO; JPO;	
DERWENT;	
IBM TDB	
	2003/05/17 09:08
or region) US-PGPUB;	
EPO; JPO;	
DERWENT;	
	2003/05/17 09:26
layer or region)) and (257/\$.ccls. or US-PGPUB;	2003/03/11 09.20
438/4.ccls.) EPO; JPO;	
DERWENT;	
IBM TDB	
3 (oxidized adj insulating adj (film or USPĀT;	2003/05/17 09:09
layer or region)) and (257/\$.ccls. or US-PGPUB;	
438/4.ccls.) and (nonvolatile adj memory) EPO; JPO;	
DERWENT;	
IBM_TDB	000010=1====
	2003/05/17 09:27
same (insulating adj (film or layer or US-PGPUB;	
region))) and (257/\$.ccls. or 438/4.ccls.) EPO; JPO;	
DERWENT;	
IBM TDB	2003/05/17 10:38
13 2 5479054.pn. and (prevent) USPAT; US-PGPUB;	2003/03/1/ 10:38
EPO; JPO;	
DERWENT;	
IBM TDB	
	2003/05/17 10:18
US-PGPUB;	,,,
EPO; JPO;	
DERWENT;	
IBM TDB	
	2003/05/17 10:03
US-PGPUB;	
EPO; JPO;	
DERWENT;	
IBM TDB	

16	1 0	5479054.pn. and (nonvolatile)	USPAT;	2003/05/17 10:18
10		orracia and (nonvoided and)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
17	0	5479054.pn. and (non adj volatile)	USPAT;	2003/05/17 10:18
			US-PGPUB; EPO; JPO;	
			DERWENT;	
	-		IBM TDB	
18	0	5479054.pn. and (memory)	USPĀT;	2003/05/17 10:19
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		5.50054	IBM_TDB	
19	0	5479054.pn. and dram	USPAT;	2003/05/17 10:19
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
20	0	5479054.pn. and sram	USPAT;	2003/05/17 10:19
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
21	0	5479054.pn. and ram	USPAT;	2003/05/17 10:20
			US-PGPUB;	
			EPO; JPO;	•
			DERWENT; IBM TDB	
22	0	5479054.pn. and prom	USPAT;	2003/05/17 10:54
22		3473034.pii. and prom	US-PGPUB;	2003/03/1% 10:54
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
23	1	5747370.pn. and (oxidized or oxidation)	USPAT;	2003/05/17 10:53
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
24	_	5747370.pn. and (sin or (silicon adj	IBM_TDB USPAT;	2003/05/17 10:54
24		nitride))	US-PGPUB;	2003/03/17 10:54
	i	nicitae, ,	EPO; JPO;	
			DERWENT;	
			IBM TDB	
25	1	5479054.pn. and (sin or (silicon adj	USPAT;	2003/05/17 10:54
		nitride))	US-PGPUB;	
ļ			EPO; JPO;	
			DERWENT;	
26	59	(/motal or /motal add silicida)) add sata)	IBM_TDB USPAT;	2003/05/17 11:56
20	39	((metal or (metal adj silicide)) adj gate) and (nonvolatile adj memory)	USPAT; US-PGPUB;	5002/03/II II:30
		and (nonvoidelie ad) memory)	EPO; JPO;	
			DERWENT;	
			IBM TDB	
27	17	((metal or (metal adj silicide)) adj gate)	USPĀT;	2003/05/17 11:56
ļ		and (nonvolatile adj memory) and tungsten	US-PGPUB;	
			EPO; JPO;	
	}		DERWENT;	
28	705	(inhamal add admonth add mariam)	IBM_TDB	2003/05/17 12:47
40	785	(peripheral adj circuit adj region) and 257/\$.ccls.	USPAT; US-PGPUB;	2003/03/1/ 12:4/
		231/9.0015.	EPO; JPO;	
			DERWENT;	
			IBM TDB	
29	256	(contact adj hole adj diameter) and	USPAT;	2003/05/17 12:48
		257/\$.ccls.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	<u> </u>

30	76	(peripheral adj circuit adj region) and	USPAT;	2003/05/17 12	2:47
		(nonvolatile adj memory) and 257/\$.ccls.	US-PGPUB;		ļ
			EPO; JPO;		l
			DERWENT;		
			IBM TDB		
31	7	(contact adj hole adj diameter) and	USPAT;	2003/05/17 12	2:48
		(nonvolatile adj memory) and 257/\$.ccls.	US-PGPUB;		
		-	EPO; JPO;		-
			DERWENT;		i
			IBM TDB		i